## NSN 5961-00-952-8418

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-952-8418 **Inclosure Material:** Glass **Overall Length:** 0.285 inches **Terminal Length:** 1.250 inches **Overall Diameter:** 0.125 inches **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 25.0 working peak off-state voltage **Voltage Tolerance In Percent:** -20.0/+20.0 **Current Rating Per Characteristic:** 0.50 microamperes repetitive peak forward current of standard range **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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